

Serial No.: 10/583,071
Examiner: Elmito Braval
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Amendments to the Claims:

This listing of claims will replace all prior versions, and listing, of claims in the application.

1. (Original) A display apparatus in which a pixel is driven by using a thin film transistor including an organic material in at least an active layer,
wherein the thin film transistor unit and a display element unit are laminated on a substrate in this order,
a pixel electrode formed on a substrate side of the display element unit also functions as a drain electrode of the thin film transistor,
a source electrode of the thin film transistor is formed so as to be opposed to the pixel electrode in a thickness direction with the active layer interposed therebetween, and
the pixel electrode has an area larger than that of the source electrode so as to cover the active layer on the source electrode substantially entirely.
2. (Cancelled)
3. (Currently amended) The display apparatus according to claim 1, wherein the source electrode has an area not less than 25% the size of the pixel electrode.
4. (Previously presented) The display apparatus according to claim 1, wherein a conductive film for suppressing gas permeation of gas and moisture is formed outside of the display element unit.
5. (Previously presented) The display apparatus according to claim 4, wherein the conductive film is formed so as to cover an entire surface of a display region.
6. (Previously presented) The display apparatus according to claim 1, wherein the substrate suppresses gas permeation of oxygen and moisture.

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7. (Previously presented) The display apparatus according to claim 1, wherein the substrate is flexible.
8. (Previously presented) The display apparatus according to claim 1, wherein the display element unit is an organic electroluminescence element.
9. (Previously presented) The display apparatus according to claim 1, wherein the active layer unit of the thin film transistor includes an organic semiconductor layer.